TOSHIBA TB2959HQ

Bi-CMOS Linear Integrated Circuit Silicon Monolithic

TB2959HQ

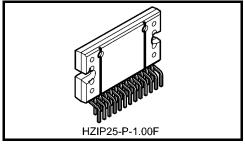
Maximum Power 47W BTL × 4-ch Audio Power IC

1. Description

The TB2959HQ is a four-channel BTL power amplifier for car audio applications.

This IC has a pure complementary P-ch and N-ch DMOS output stage, offering maximum output power (POUT MAX) of 47W.

It includes a standby switch, mute function and various protection features.



Weight: 7.7 g (typ.)

2. Applications

Power IC developed for car audio applications.

3. Features

- High output power, low distortion, and low noise property (for details, refer to the Table 1)
- Build-in AUX-IN (pin25)
- Built-in various mute functions (low voltage, standby on/off)
- Built-in standby switch (pin4)
- Built-in mute switch (pin22)
- Built-in various protection circuits (thermal shut down, over-voltage, short to GND, short to VCC, and output to output short)

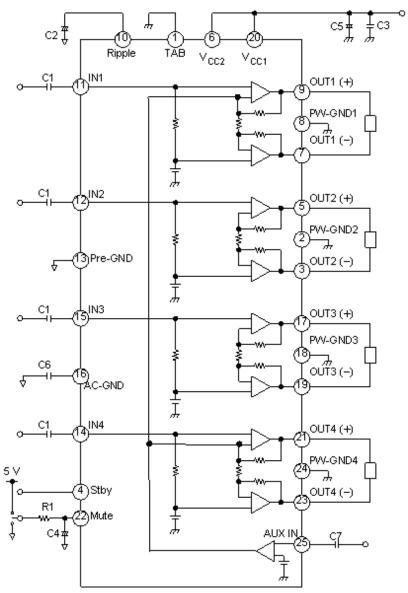
Table1 typical Characteristics (Note1,Note2)

| Condition | T | l lmit | | | | |
|---|---------|--------|--|--|--|--|
| Condition | Тур. | Unit | | | | |
| Output power (| Роит) | | | | | |
| V _{CC} = 15.2 V, JEITA max | 47 | | | | | |
| V _{CC} = 14.4 V, JEITA max | 42 | W | | | | |
| V _{CC} = 14.4 V, THD = 10% | 27 | VV | | | | |
| THD = 10% | 23 | | | | | |
| Total harmonic distortion (THD) | | | | | | |
| P _{OUT} = 5 W | 0.005 | % | | | | |
| Output noise voltage (V_{NO}) (Rg = 0 Ω), | | | | | | |
| BW = 20 Hz to 20 kHz | 50 | μV | | | | |
| Operating Supply voltage range (V _{CC}) | | | | | | |
| R _L = 4 Ω | 6 to 18 | V | | | | |

Note1: Typical test conditions: $V_{CC} = 13.2 \text{ V}$, f = 1 kHz, $R_L = 4 \Omega$, $G_V = 26 \text{ dB}$, $T_A = 25 ^{\circ}\text{C}$; unless otherwise specified.

Note2: Rg: signal source resistance

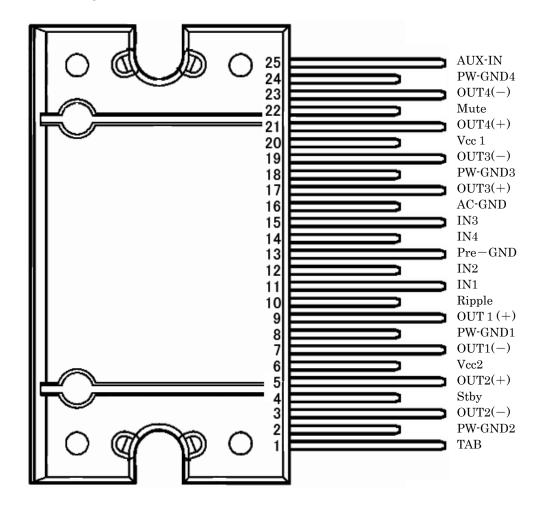
4. Block Diagram



Note3: Some of the functional blocks, circuits or constants may be omitted from the block diagram or simplified for explanatory purposes. In the following explanation, a "channel" is a circuit which consists of INx, OUTx (+), OUTx (-), and PW-GNDx. (x:1 to 4)

5. Pin Configuration and Function Descriptions

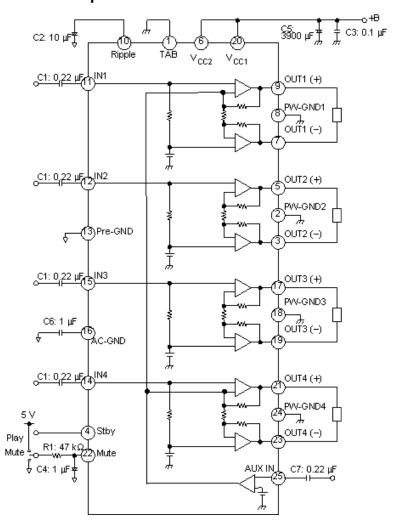
5.1 Pin Configuration (top view)



5.2 Pin Function Descriptions

| Pin | Symbol | I/O | Description |
|-----|------------------|----------------------|--|
| 1 | TAB | _ | TAB (Always connect with GND) |
| 2 | PW-GND2 | _ | Ground for Rear Left output |
| 3 | OUT2(-) | OUT | Rear Left output- |
| 4 | Stby | V _{ST} -IN | Standby voltage input |
| 5 | OUT2(+) | OUT | Rear Left output+ |
| 6 | V _{CC2} | V _{CC} -IN | Supply voltage 2 |
| 7 | OUT1(-) | OUT | Front Left output- |
| 8 | PW-GND1 | _ | Ground for Front Left output |
| 9 | OUT1(+) | OUT | Front Left output+ |
| 10 | Ripple | _ | Ripple voltage |
| 11 | IN1 | IN | Front Left input |
| 12 | IN2 | IN | Rear Left input |
| 13 | Pre-GND | _ | Signal ground |
| 14 | IN4 | IN | Rear Right input |
| 15 | IN3 | IN | Front Right input |
| 16 | AC-GND | _ | Common reference voltage for all input |
| 17 | OUT3(+) | OUT | Front Right output+ |
| 18 | PW-GND3 | _ | Ground for Front Right output |
| 19 | OUT3(-) | OUT | Front Right output- |
| 20 | V _{CC1} | V _{CC} -IN | Supply voltage 1 |
| 21 | OUT4(+) | OUT | Rear Right output+ |
| 22 | Mute | V _{mute} IN | Mute voltage input |
| 23 | OUT4(-) | OUT | Rear Right output- |
| 24 | PW-GND4 | _ | Ground for Rear Right output |
| 25 | AUX-IN | IN_Beep | BEEP sound or voice synthesizer signal input |

6. Detailed Description



| Component | Recomm | | | Effect (Note4) | | | | |
|-----------|----------------|-------------------------------------|--|---|---|--|--|--|
| Name | ended Value | Pin | Purpose | Lower than Recommended Value | Higher than Recommended Value | | | |
| C1 | 0.22 μF | INx(x:1 to 4) | To eliminate DC | Cut-off frequency becomes higher | Cut-off frequency becomes lower | | | |
| C2 | 10 μF | Ripple | To reduce ripple | Turn on/off time and turn-on diag. cycle shorter | Turn on/off time and turn-on diag. cycle longer | | | |
| C3 | 0.1 μF | V _{CC1} , V _{CC2} | To provide sufficient oscillation margin | Reduces noise and provides sufficient oscillation margin | | | | |
| C4 | 1uF | Mute | To reduce pop noise | High pop noise. Duration until mute function is turned on/off is short. | Low pop noise. Duration until mute function is turned on/off is long. | | | |
| C5 | 3900 μF | V _{CC1} , V _{CC2} | Ripple filter | Power supply ripple filtering | | | | |
| C6 | 1 μF | AC-GND | Common reference voltage for all input | Pop noise is suppressed when C1: C6 = 1:4. (Note5) | | | | |
| C7 | 0.22μF | AUX-IN | To eliminate DC | Cut-off frequency is increased in AUX | Cut-off frequency is reduced in AUX. | | | |
| R1 | 47 kΩ | Mute | To reduce pop noise | High pop noise. Duration until mute function is turned on/off is short. | Low pop noise. Duration until mute function is turned on/off is long. | | | |

Note4: When the unrecommended value is used, please examine it enough by system evaluation.

Note5: Since "AC-GND" pin is a common reference voltage for all input, this product needs to set the ratio of an input apacitance (C1) and the AC-GND capacitance (C6) to 1:4.

7. Standby Switch

The power supply can be turned on or off via pin 4 (Stby). The threshold voltage of pin 4 is set at about 3 VBE (typ.). The power supply current is about 0.01 μA (typ.) in the standby state.

Table1 Standby Control Voltage (V_{SB})

| Stand-by | Power | V _{SB} (V) |
|----------|-------|------------------------|
| ON | OFF | 0 to 0.9 |
| OFF | ON | 2.2 to V _{CC} |

Check the pop levels when the time constant of pin 4 is changed.

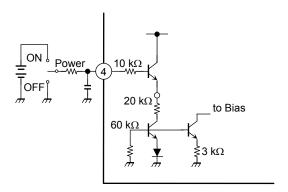


Figure 1 Setting Pin 4 High Turns on Power

Benefits of the Standby Switch

- (1) VCC can be directly turned on or off by a microcontroller, eliminating the need for a switching relay.
- (2) Since the control current is minuscule, a low-current-rated switching relay can be used.

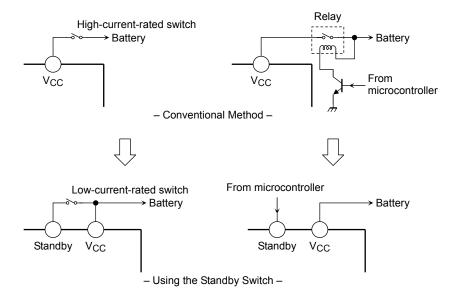


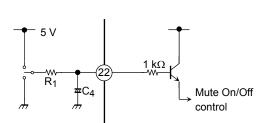
Figure 2 Standby Switch

8. Mute switch

The audio mute switch is enabled by setting pin 22 Low. R₁ and C₄ determine the time constant of the mute. The time constant affects pop noise generated when power or the mute is turned on or off; thus, it must be determined on a per-application basis.

The value of the external pull-up resistor is determined, based on pop noise value.

For example, when the control voltage is changed from 5 V to 3.3 V, the pull-up resistor should be: 3.3 V/5 V \times 47 k Ω = 31 k Ω



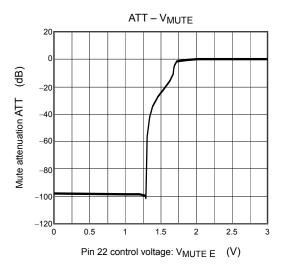


Figure 3 Mute Function

Figure 4 Mute Attenuation—V_{MUTE} (V)

9. Mute Mode

The mute mode in this product is a mute at standby on/off, an internal mute for low voltage. If the mute is turned off before charging C1 and C4 is finished, pop noise occurs because of input offset. Set "mute-off" with sufficient margin in considering a charge time.

9.1 Low Voltage Mute

Low Voltage Mute is operated inside the IC the Ripple pin voltage becomes about under the about 5.6V.

9.2 Standby off Mute

A mute operation starts automatically inside the IC after standby-low until the Ripple pin voltage becomes about $1/2 \, \text{Vcc-}0.7 \text{V}$.

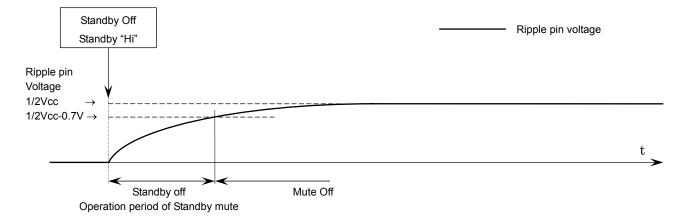


Figure 5 Standby Off Mute

10. AUX-Input

The pin 25 is for input terminal of AUX amplifier. The total gain is 0dB by using of AUX amplifier. Therefore, the μ -COM can directly drive the AUX amplifier. BEEP sound or voice synthesizer signal can be input to pin 25 directly.

When AUX function is not used, this pin must be connected to PRE-GND (pin 13) via a capacitor.

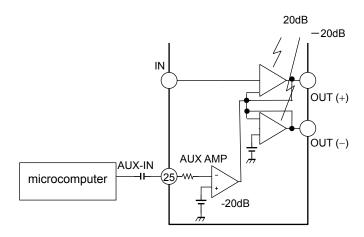


Figure 6 AUX-Input

11. Protection Functions

This product has internal protection circuits such as thermal shut down, over-voltage, out to VCC, out to GND, and out to out short circuit protections.

(1) Thermal shut down

It operates when junction temperature exceeds 150°C (typ.). When it operates, it is protected in the following order.

- 1. An Attenuation of an output starts first and the amount of attenuation also increases according to a temperature rising,
- 2. All outputs become in a mute state, when temperature continues rising in spite of output attenuation.
- 3. Shutdown function starts, when a temperature rise continues though all outputs are in a mute state.

In any case if temperature falls, it will return automatically.

(2) Over-voltage

It operates when voltage exceeding operating range is supplied to VCC pin. If voltage falls, it will return automatically. When it operates, output bias is turned off and an output is intercepted.

(3) Short to Vcc, Short to GND, Output to output short

It operates when each pin is in irregular connection. If irregular connection is canceled, it will return automatically.

Short circuit protection can operate for each channel.

When it operates, output bias of corresponding output is turned off and an output is intercepted. Example) If channel 1 output shorts, channel 1 is protected but other channels 2 to 4 are available.

(4) Prevention of speaker damage (in case of a layer short-circuit of the speaker)

When the DC resistance between the OUT+ and OUT- pins falls below 1 Ω , the output current exceeds 4 A. At this time, the protection circuit is activated to limit the current draw into the speaker. This feature prevents the speaker from being damaged, as follows:

< Speaker damaging scenario >

A DC current of over 4 V is applied to the speaker due to an external circuit failure (Note 6). (Abnormal DC output offset)

The speaker impedance becomes 1Ω or less due to a layer short.

A current of over 4 A flows into the speaker, damaging the speaker.

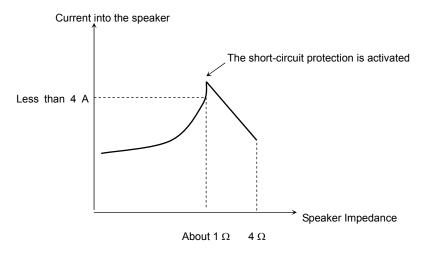


Figure 7 Prevention of speaker damage

Note 6: An abnormal DC offset voltage is incurred when the input bias to the power IC is lost due to a leakage current from a coupling capacitor at the input or a short-circuit between the IN and adjacent lines.

12. Absolute Maximum Ratings

| Characteristics | Condition | Symbol | Rating | Unit |
|-----------------------------|-----------|-------------------------|------------|------|
| supply voltage (surge) | max0.2s | V _{CC} (surge) | 50 | V |
| supply voltage (DC) | | V _{CC} (DC) | 25 | ٧ |
| supply voltage (operation) | | V _{CC (opr)} | 18 | ٧ |
| output current (peak) | | I _{O (peak)} | 9 | Α |
| power dissipation | (Note7) | P_{D} | 125 | W |
| Operating temperature range | | T _{opr} | -40 to 85 | °C |
| Storage temperature | | T _{stg} | -55 to 150 | °C |

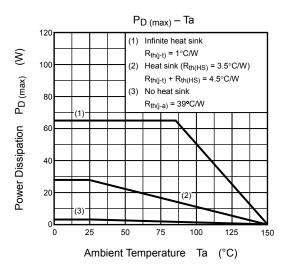
Note7: Package thermal resistance $R_{th(j-t)} = 1^{\circ}C/W$ (typ.) (Ta = 25°C, with infinite heat sink)

The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed. Moreover, these operations with exceeded ratings may cause break down, damage, and/or degradation to any other equipment. Applications using the device should be designed such that each maximum rating will never be exceeded in any operating conditions.

Before using, creating, and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

12.1 Power Dissipation



13. Operating Ranges

| Characteristics | Symbol | Condition | Min | Тур. | Max | Unit |
|-----------------|-----------------|--------------------|-----|------|-----|------|
| Supply voltage | V _{CC} | R _L =4Ω | 6 | _ | 18 | V |

14. Electrical Characteristics

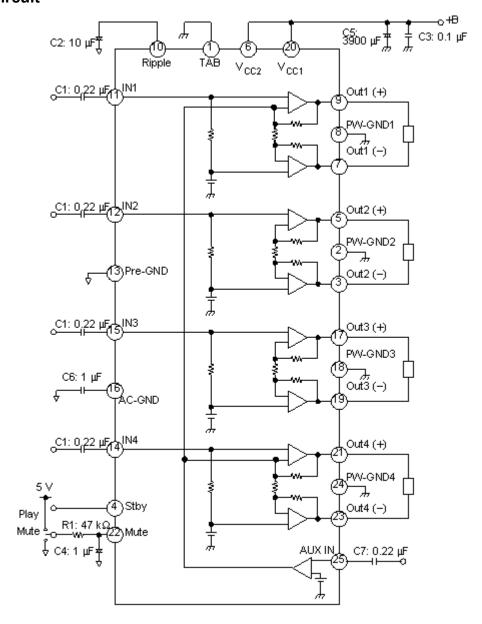
(V_{CC} = 13.2 V, f = 1 kHz, R_L = 4 Ω , G_V=26dB, Ta = 25°C unless otherwise specified)

| | (100 101 | , - | 1 K112, KL = 4 12, Gy=200B, 1a = 2 | | | | | |
|---------------------------------|--------------------------|-----------------|--|------------------------|-------|----------|-------|--|
| Characteristics | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit | |
| Quiescent supply current | Iccq | _ | V _{IN} = 0 | _ | 160 | 300 | mA | |
| | P _{OUT} MAX (1) | _ | V _{CC} = 15.2 V, max POWER | | 47 | _ | | |
| Output power | P _{OUT} MAX (2) | _ | V _{CC} = 14.4 V, max POWER | _ | 42 | _ | w | |
| Output power | P _{OUT} (1) | _ | V _{CC} = 14.4 V, THD = 10% | 14.4 V, THD = 10% — 27 | | | - vv | |
| | P _{OUT} (2) | _ | THD = 10% | 21 | 23 | | | |
| Total harmonic distortion | THD | _ | P _{OUT} = 5 W | | 0.005 | 0.07 | % | |
| Voltage gain | G _V | _ | V _{OUT} = 0.775 Vrms | 25 | 26 | 27 | dB | |
| Channel-to-channel voltage gain | ΔG _V | _ | V _{OUT} = 0.775 Vrms | -1.0 | 0 | 1.0 | dB | |
| Output noise voltage | V _{NO} (1) | _ | $R_g = 0 \Omega$, DIN45405 | | 50 | | μVrms | |
| Output noise voitage | V _{NO} (2) | _ | $R_g = 0 \ \Omega$, BW = 20 Hz to 20 kHz | | 50 | 70 | | |
| Ripple rejection ratio | R.R. | _ | f_{rip} = 100 Hz, R _g = 620 Ω (Note9) V _{rip} = 0.775 Vrms | 50 | 70 | | dB | |
| Crosstalk | C.T. | _ | $R_g = 620 \Omega$ $P_{OUT} = 4 W$ | | 80 | | dB | |
| Output offset voltage | Voffset | _ | _ | -90 | 0 | 90 | mV | |
| Input resistance | R _{IN} | _ | _ | | 90 | _ | kΩ | |
| Standby current | I _{SB} | _ | Standby condition, V4 = 0, V22 = 0 | | 0.01 | 1 | μА | |
| Standby control voltage | V _{SB} H | _ | POWER: ON | 2.2 | _ | V_{CC} | V | |
| Standby Control Voltage | V _{SB} L | _ | POWER: OFF | 0 | _ | 0.9 | V | |
| Mute control voltage | V _M H | _ | MUTE: OFF | 2.2 | _ | Vcc | V | |
| mute control voltage | V _M L | _ | MUTE: ON, $R_1 = 47 \text{ k}\Omega$ | 0 | _ | 0.9 | 7 V | |
| Mute attenuation | ATT M | _ | MUTE: ON, DIN_AUDIO V _{OUT} = 7.75 Vrms → Mute: OFF | 85 | 100 | _ | dB | |
| Upper cut-off frequency | F _{th} | _ | G _V = 26dB, 3dB down | _ | 400 | _ | kHz | |

Note9: f_{RIP} Ripple frequency

V_{RIP} Ripple signal voltage (AC fluctuations in the power supply)

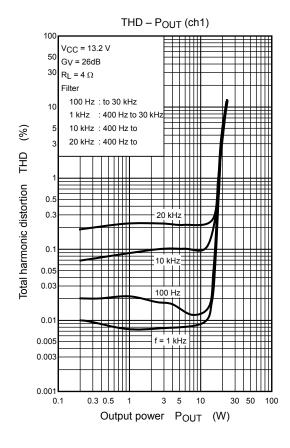
15. Test Circuit

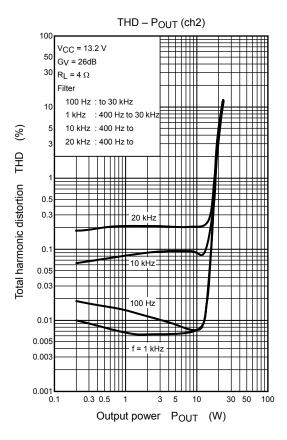


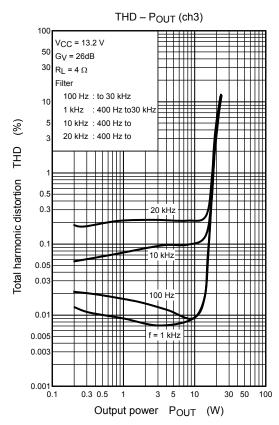
Components in the test circuits are only used to obtain and confirm the device characteristics.

16. Characteristic Chart

16.1 Total Harmonic Distortion vs. Output Power







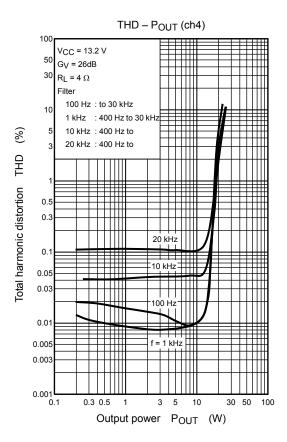


Figure 11-1 Total Harmonic Distortion of Each Frequency ($R_L = 4 \Omega$)

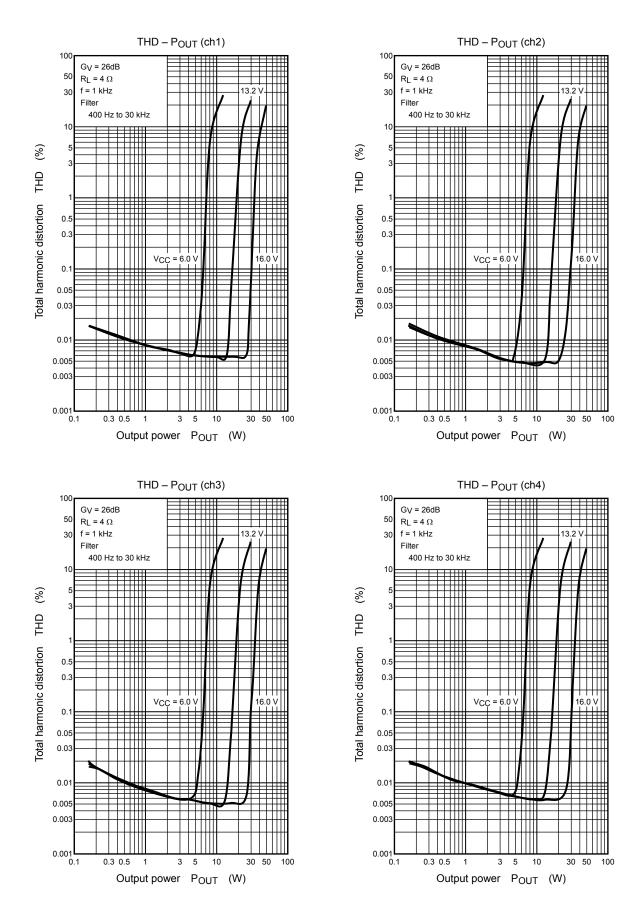


Figure 11-2 Total Harmonic Distortion by Power-supply Voltage ($R_L = 4 \Omega$)

16.2 Various Frequency Characteristics

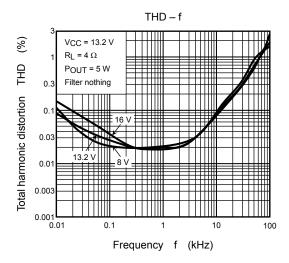


Figure 11-3 Frequency Characteristics of Total Harmonic Distortion

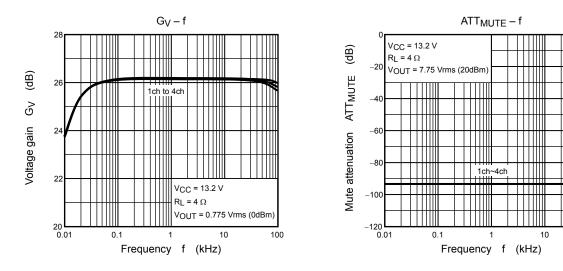


Figure 11-4 Frequency Characteristics of Voltage Gain and Mute Attenuation

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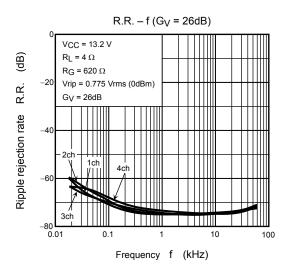


Figure 11-5 Frequency Characteristics of Ripple Rejection Rate

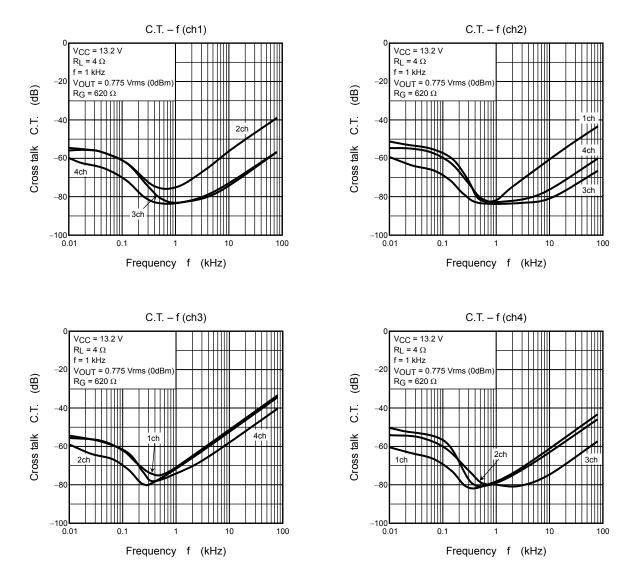
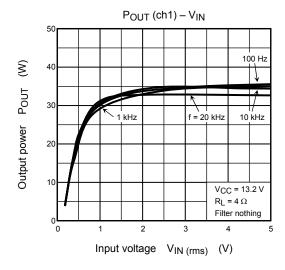
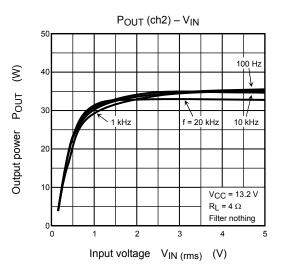
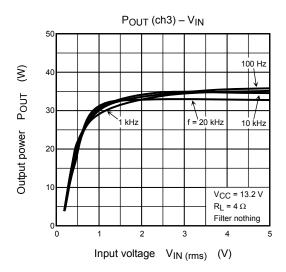


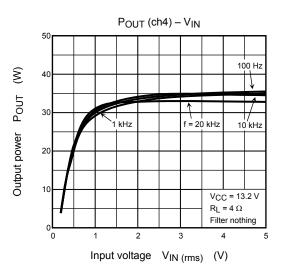
Figure 11-6 Frequency Characteristics of Cross Talk

16.3 Output Power Characteristics to Input Voltage

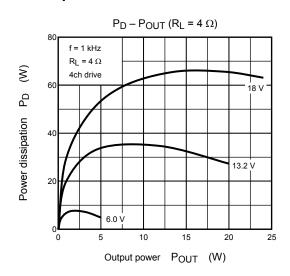




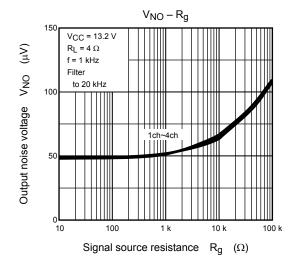


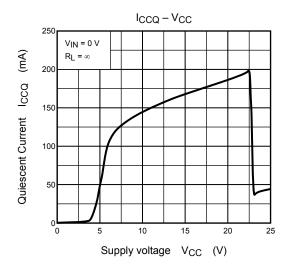


16.4 Power Dissipation vs. Output Power



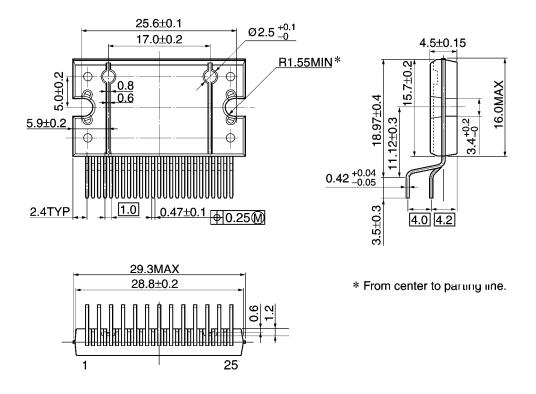
16.5 Other Characteristic





17. Package Dimensions

HZIP25-P-1.00F Unit: mm



Weight: 7.7g (typ.)

About solderability, following conditions were confirmed.

- (1) Use of Sn-37Pb solder Bath
 - solder bath temperature = 230°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux
- (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - solder bath temperature = 245°C
 - dipping time = 5 seconds
 - the number of time = once
 - use of R-type flux

18. 4ch Power IC Evaluation Board

This drawing is a component side, and a schematic diagram of evaluation board "RP-2024 for 4ch power IC using HZIP25-P-1.00F (SPP25), a solder side.

Note: This board can be shared with some products.

Please confirm external parts of the evaluated product beforehand when you unite the evaluation board.

• Component side

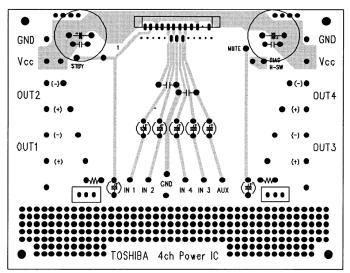


Figure 18-1 Pattern of Evaluation Board (component side)

• Solder side

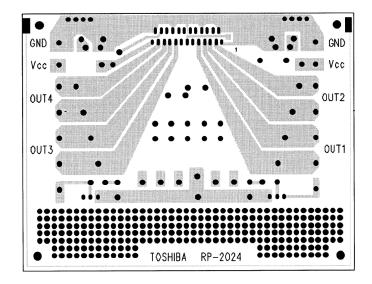


Figure 18-2 Pattern of Evaluation Board (solder side)

19. Attention in Use

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of
 over current and/or IC failure. The IC will fully break down when used under conditions that exceed its
 absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs
 from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke
 or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate
 settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the
 design to prevent device malfunction or breakdown caused by the current resulting from the inrush
 current at power ON or the negative current resulting from the back electromotive force at power OFF. For
 details on how to connect a protection circuit such as a current limiting resistor or back electromotive
 force adsorption diode, refer to individual IC datasheets or the IC databook. IC breakdown may cause
 injury, smoke or ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load
 components (such as speakers), for example, power amp and regulator. If there is a large amount of
 leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If
 this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure
 can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In
 particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs
 output DC voltage to a speaker directly.
- Over current Protection Circuit
 Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.
- Thermal Shutdown Circuit
 Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the Thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.
- Heat Radiation Design When using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.
 - Installation to Heat Sink
 Please install the power IC to the heat sink not to apply excessive mechanical stress to the IC. Excessive mechanical stress can lead to package cracks, resulting in a reduction in reliability or breakdown of internal IC chip. In addition, depending on the IC, the use of silicon rubber may be prohibited. Check whether the use of silicon rubber is prohibited for the IC you intend to use, or not. For details of power IC heat radiation design and heat sink installation, refer to individual technical datasheets or IC databooks.

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